



Cornell Laboratory for
Accelerator-based Sciences
and Education (CLASSE)



Impurity Doping of Superconducting Radio Frequency Cavities

Peter N. Koufalis
Cornell University
May 5th, 2016



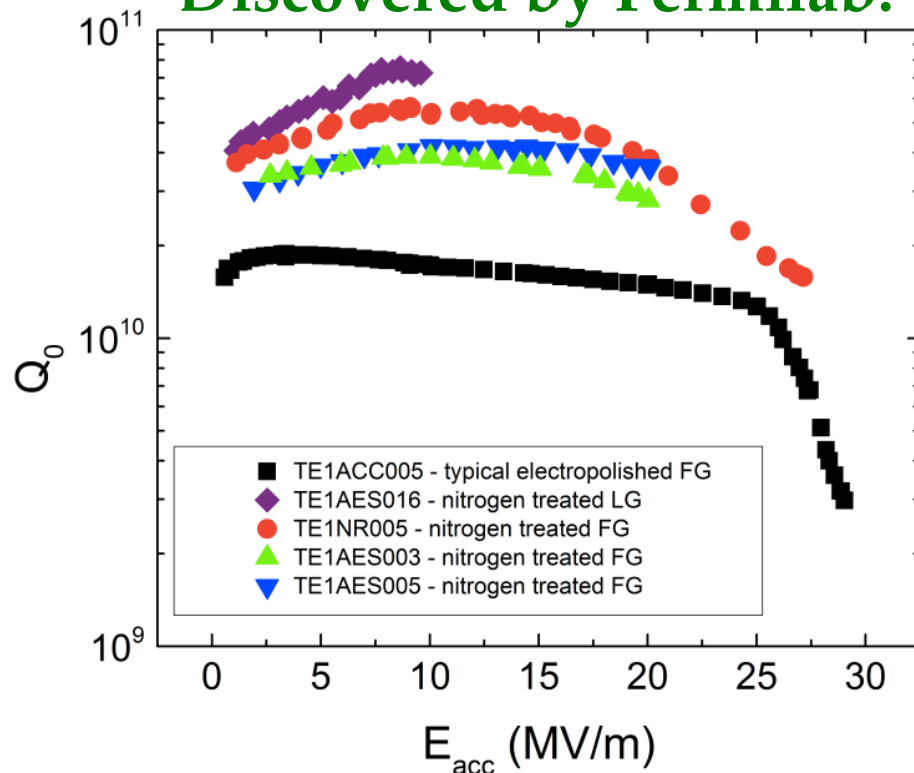
• Nitrogen doping

- Why dope?
- Benefits of N-doping
- Nitrogen Doping Process
- Field dependence of surface resistance
- Drawbacks of N-doping

• Inert Dopants

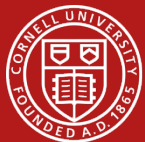
- Why alternative dopants?
- Argon
- Helium

Discovered by Fermilab:

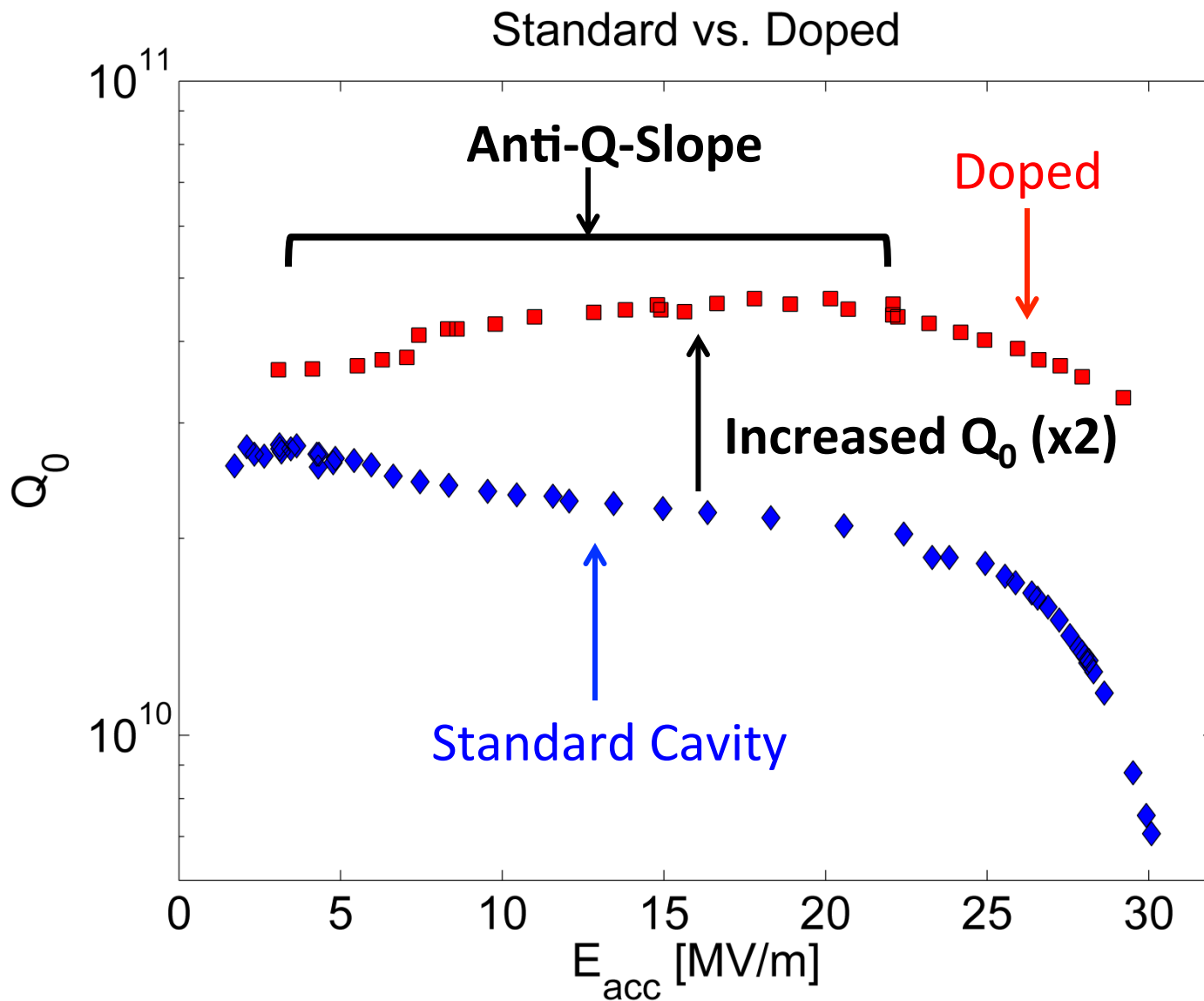


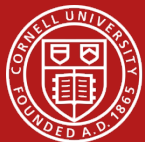
A. Grassellino et al. *Supercond. Sci. Tech.*,
26(102001), 2013.

$$Q_0 = \omega_0 U / P_c$$



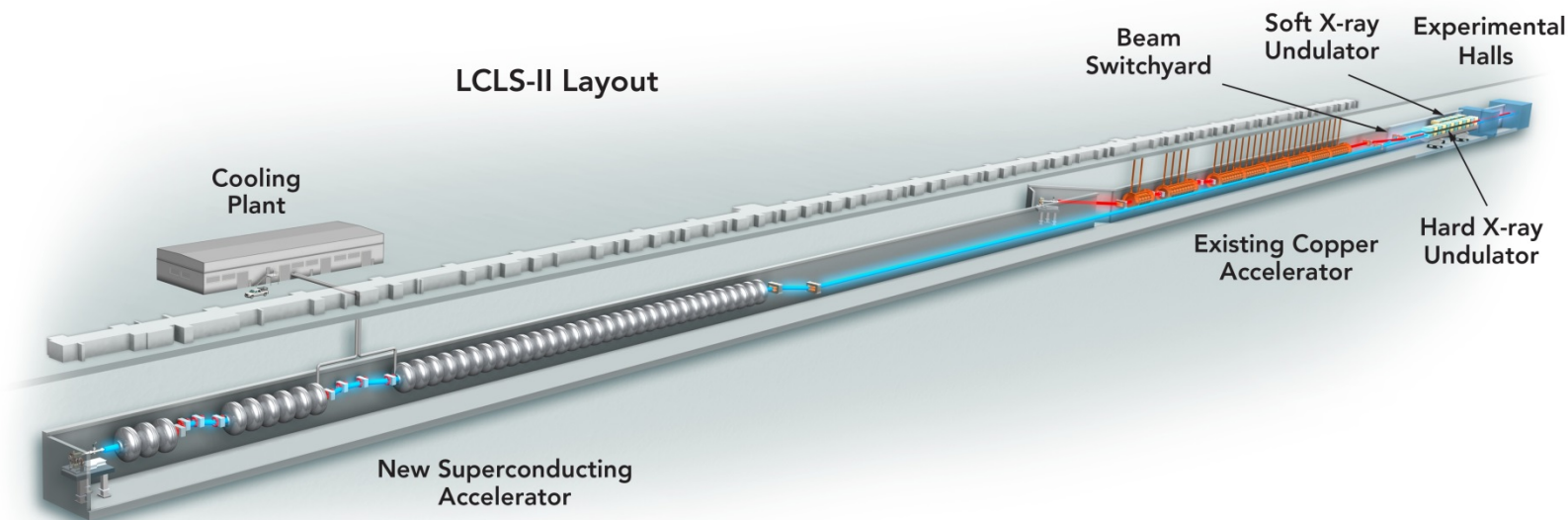
Why Dope?



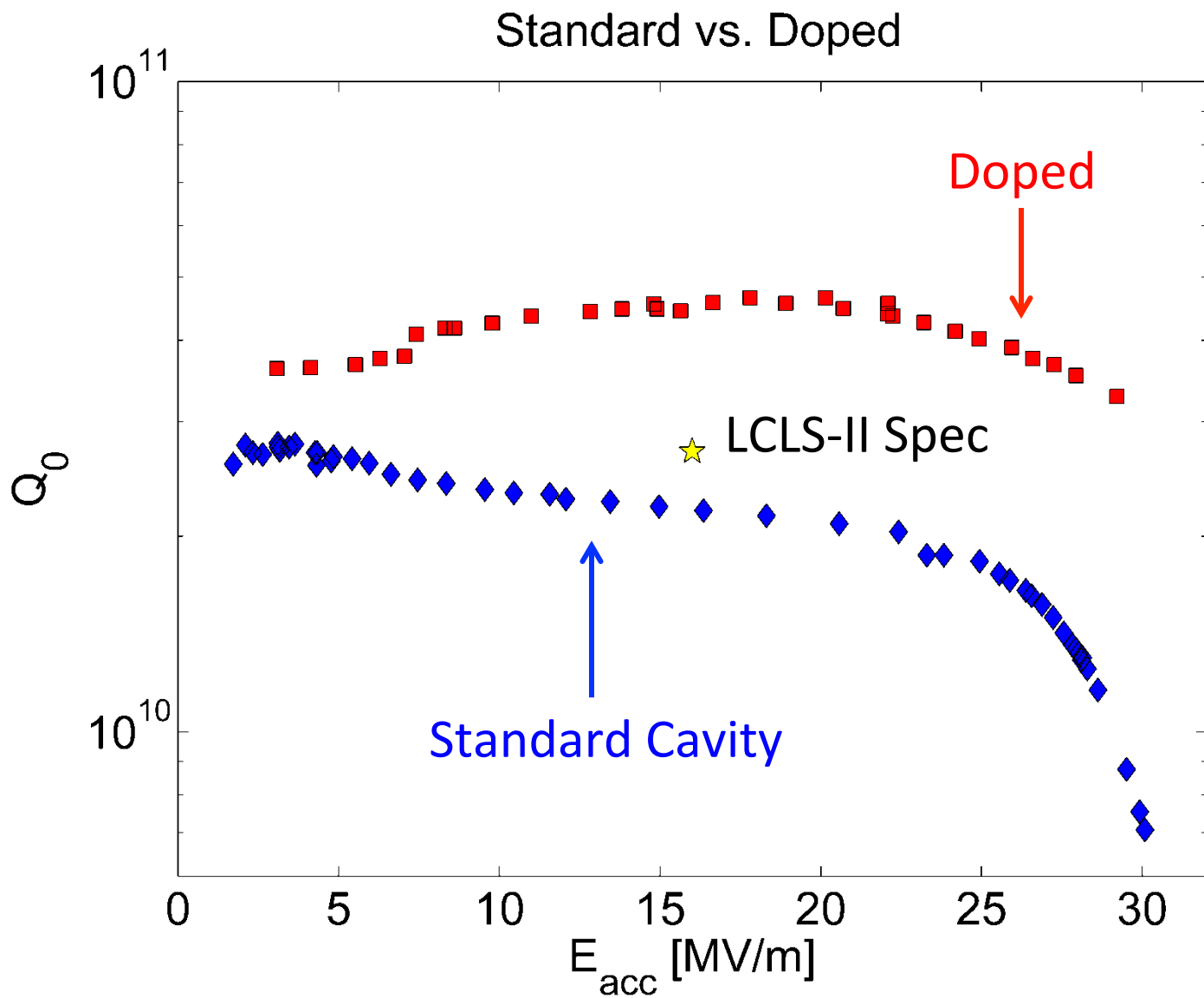
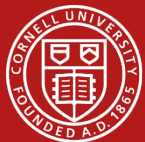


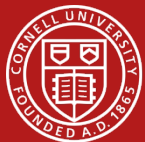
- N-doped 9-cell cavities
- Increased efficiency
- Lower operating costs

Cryogenic losses $\sim 1/Q_0$

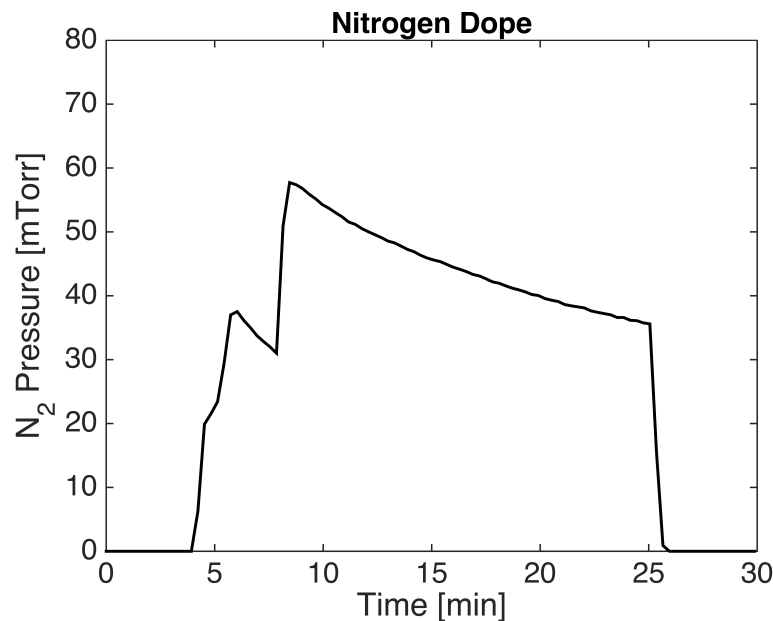
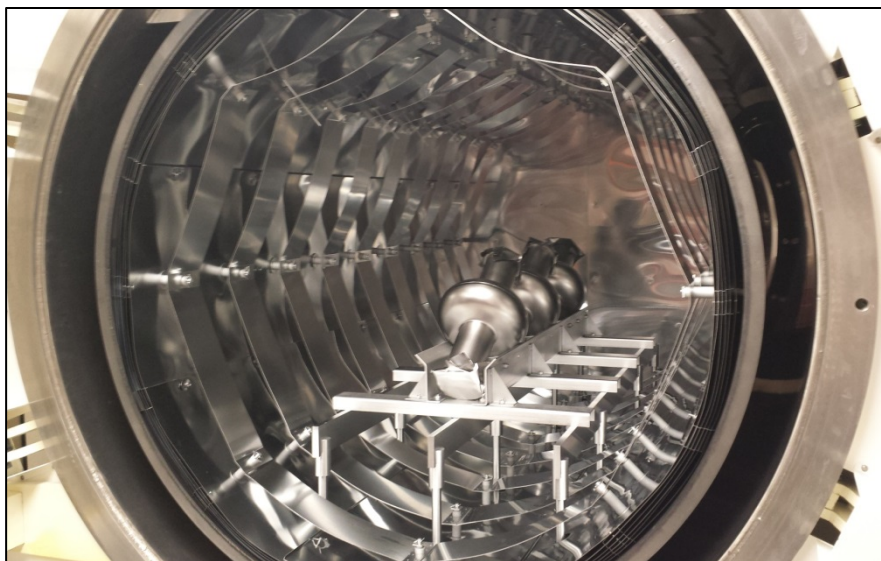


*Courtesy of SLAC National Accelerator Laboratory





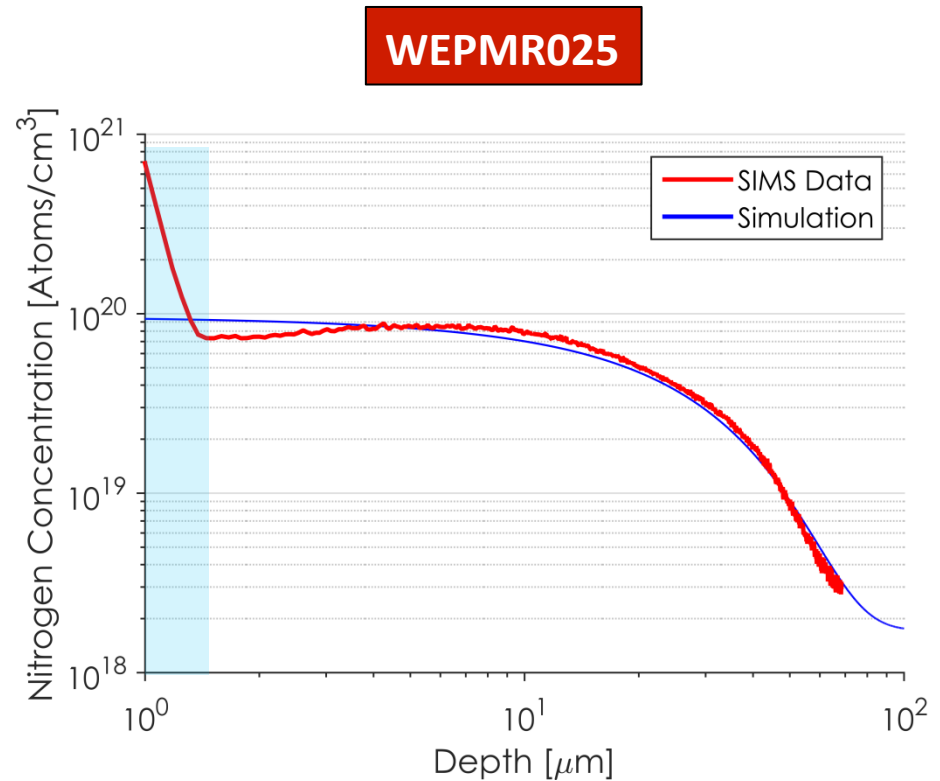
TM Vacuum Furnace

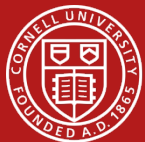


Recipe:

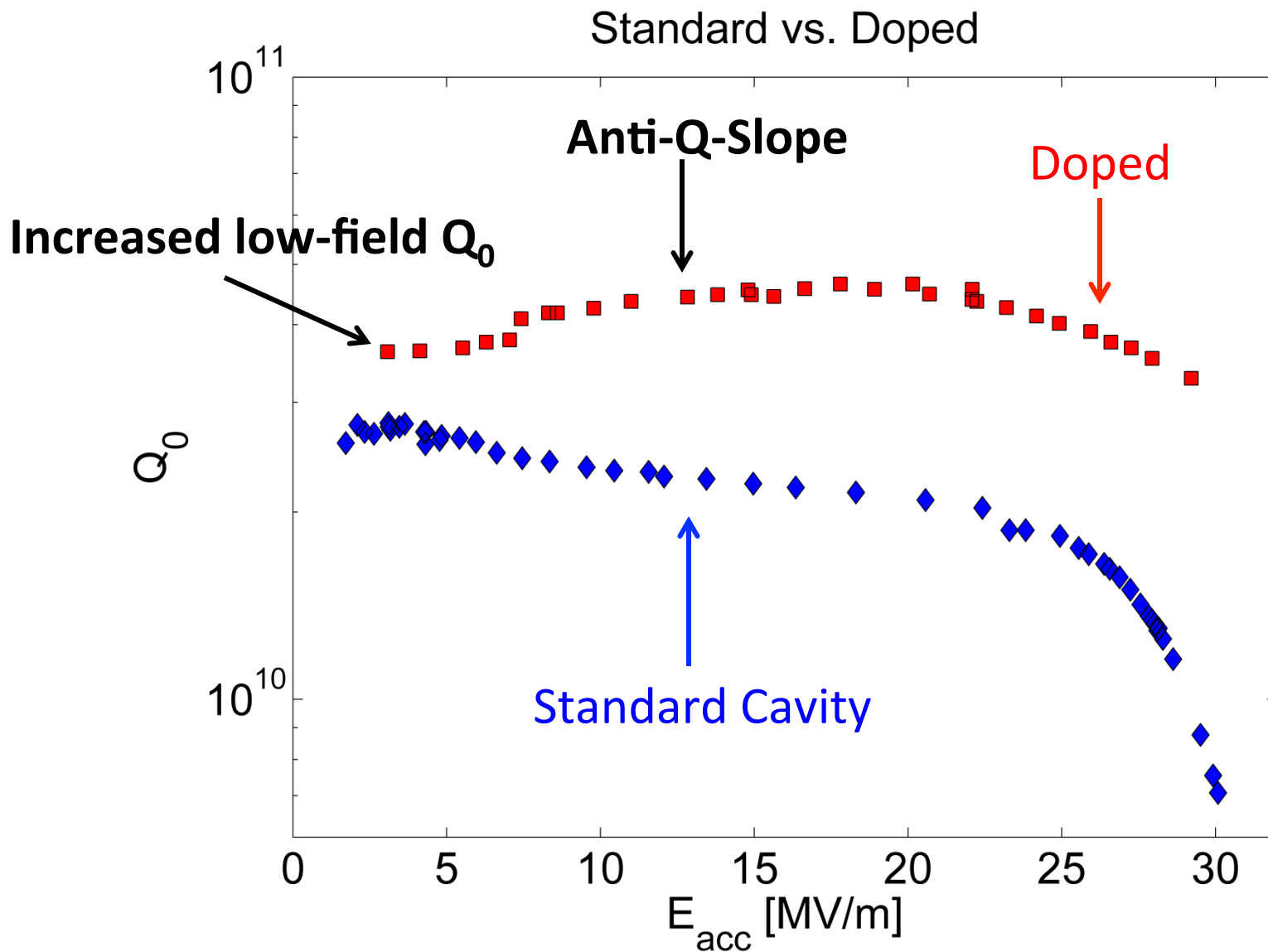
1. Dope
 - 800 °C / 20 mins / 60 mTorr N₂
2. Anneal Step
 - 800 °C / 30 mins / Vacuum

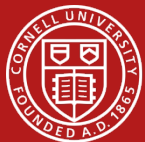
- Cavities doped in a vacuum furnace at high temperatures
- NbN forms on the surface of the cavity
- Nitrogen diffuses from the NbN layer into the Nb bulk as an interstitial
- Chemical etching is performed to remove the *lossy* NbN layer



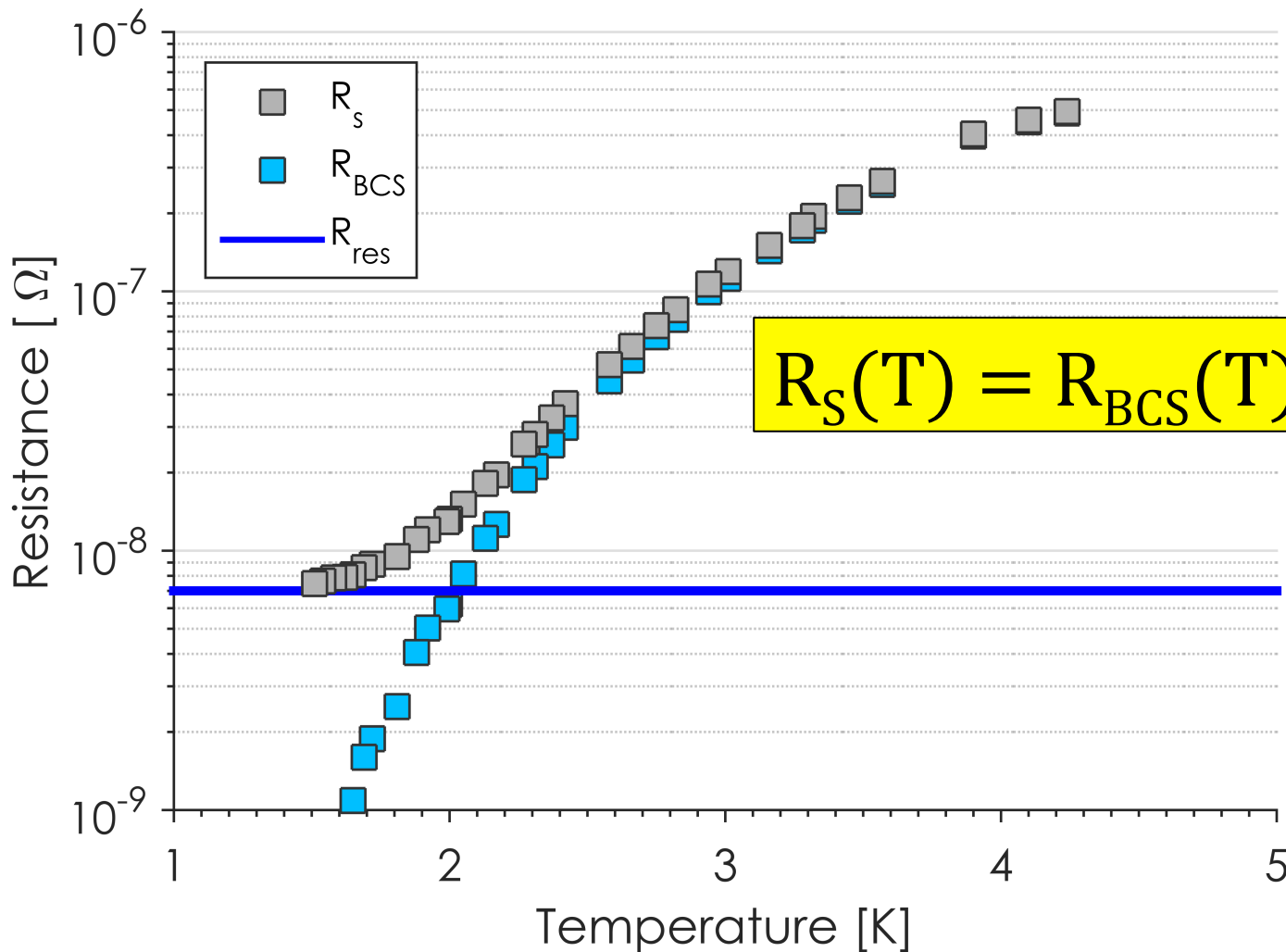


What is Nitrogen Doping?





Surface Resistance



$$R_s(T) = R_{BCS}(T) + R_0$$

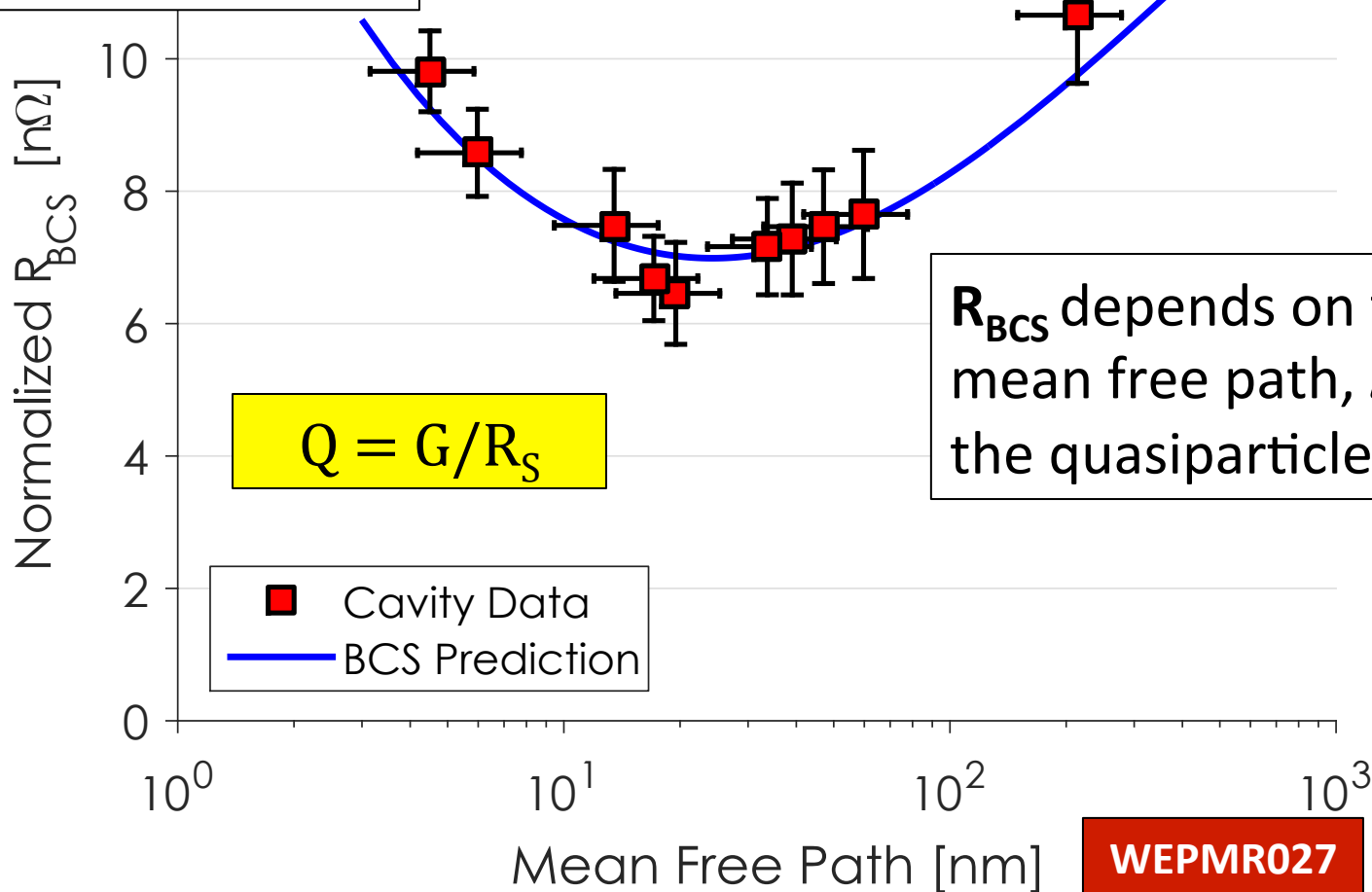




Low Field BCS Resistance

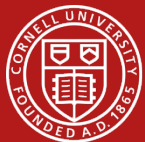


Nitrogen doping brings l to optimal region to minimize low field resistance

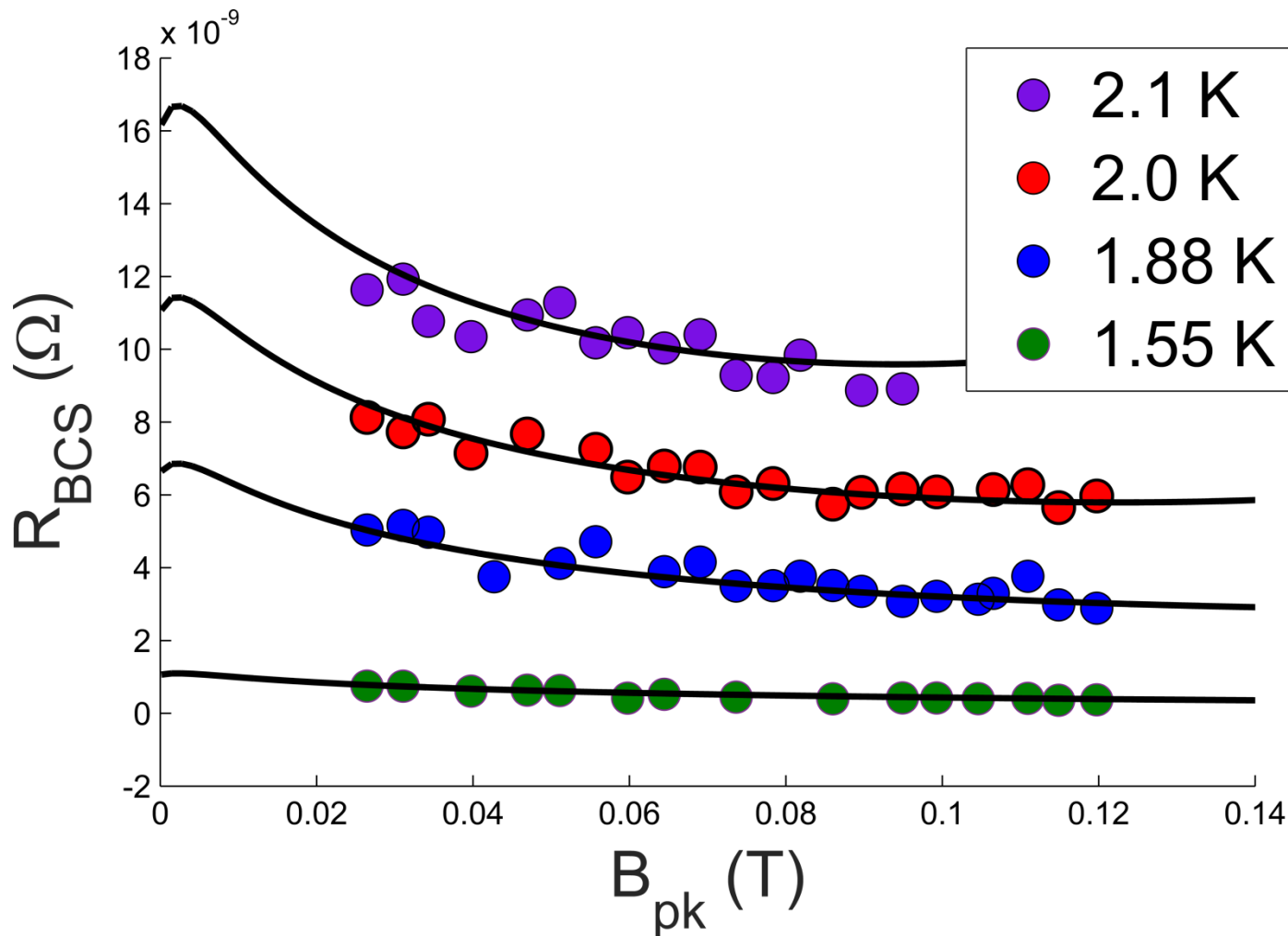


WEPMR027

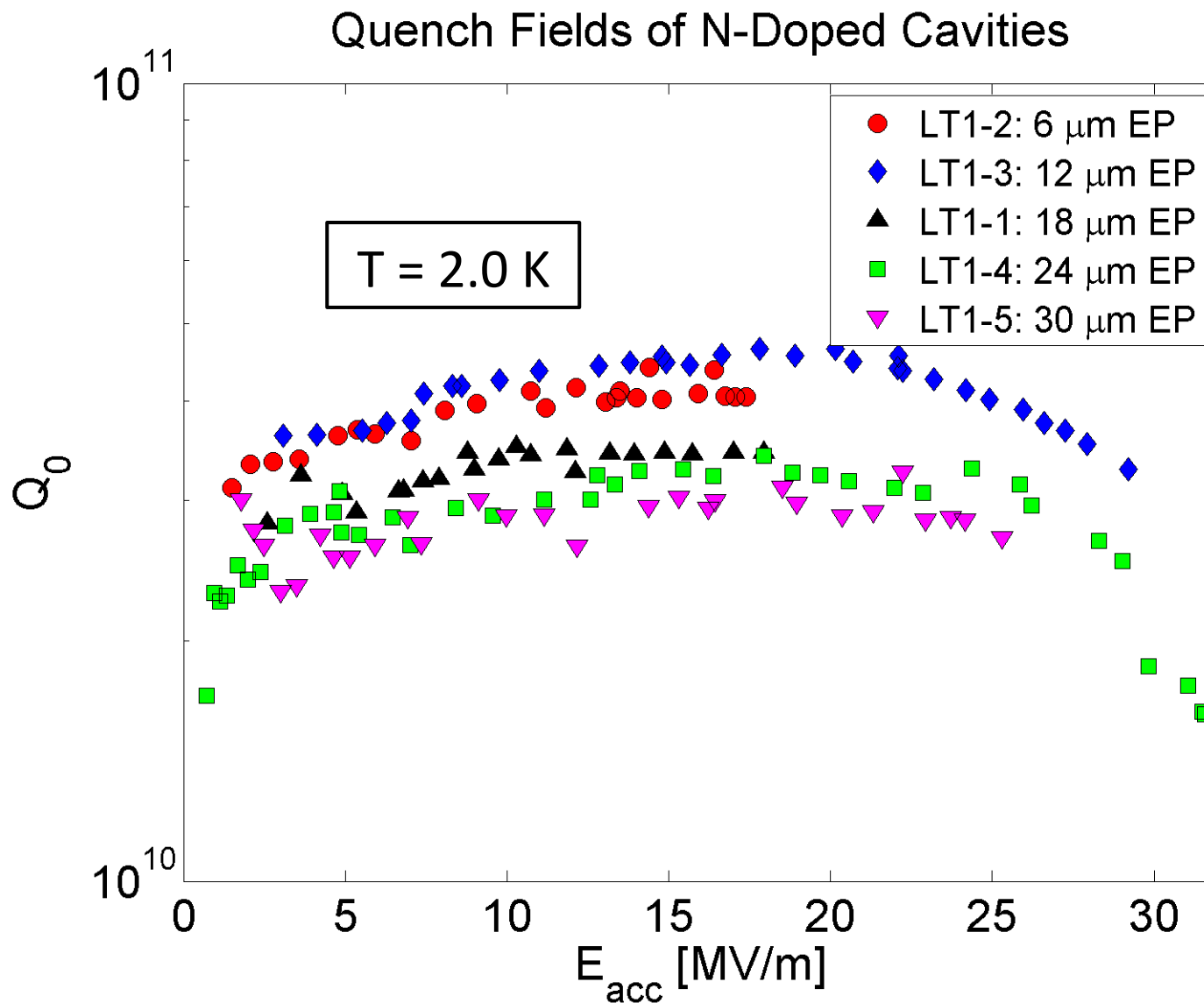
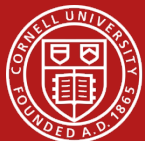


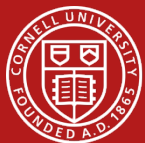


Field Dependence



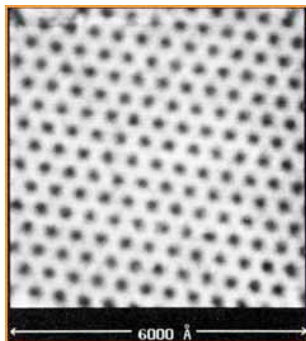
A. Gurevich. Phys. Rev. Lett. 113:087001, Aug. 2014.



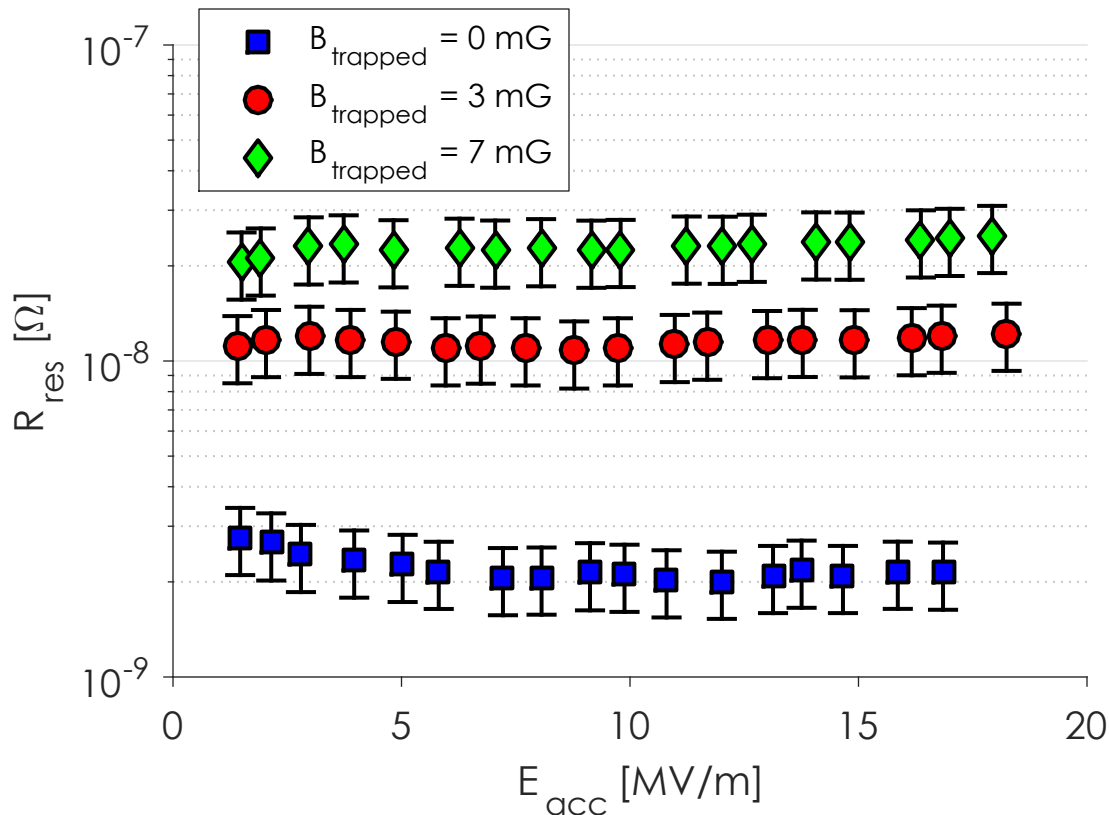


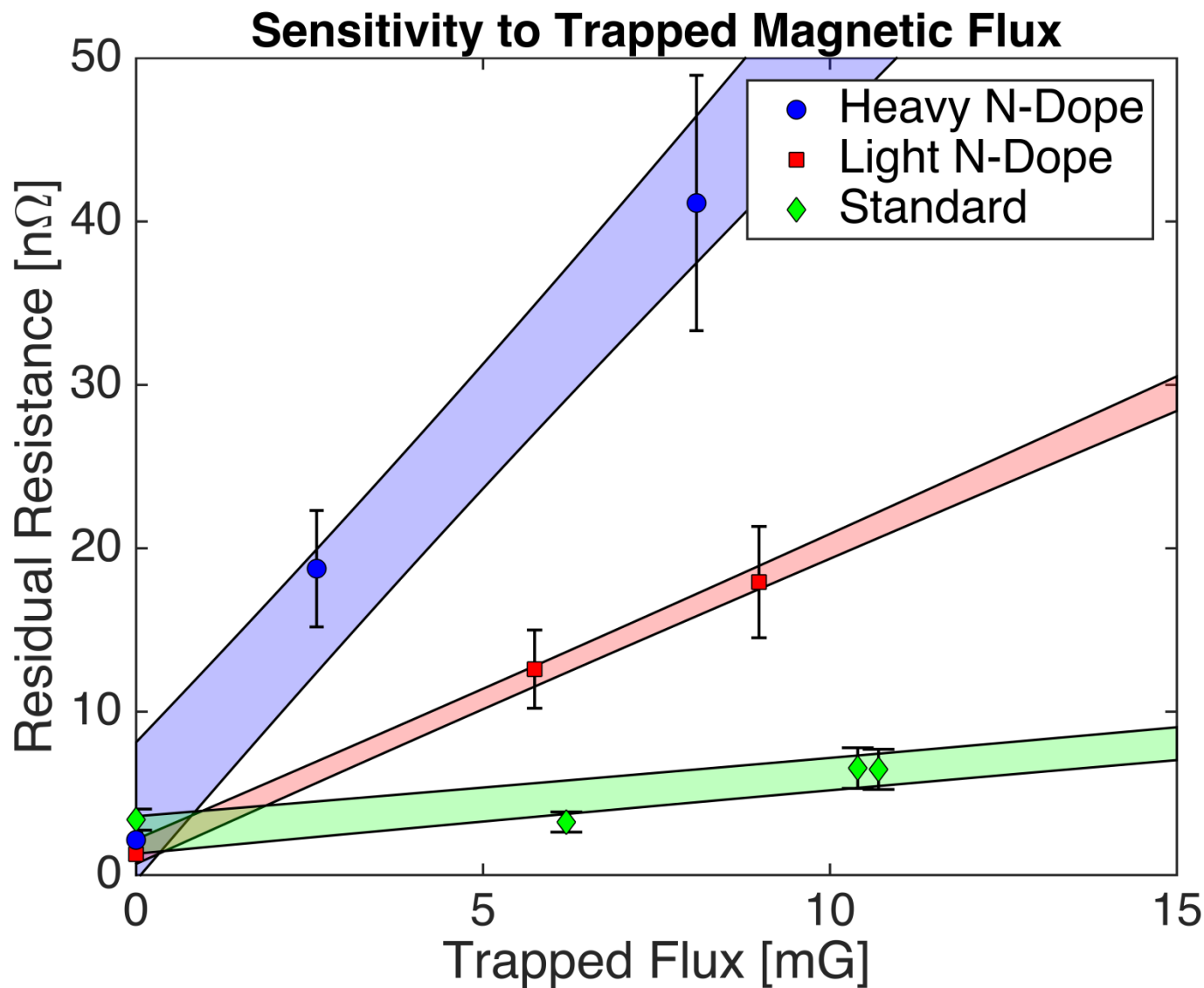
Cornell Laboratory for
Accelerator-based Sciences
and Education (CLASSE)

RF Losses from Trapped Magnetic Flux

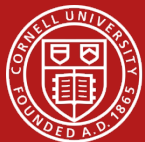


Phys. Rev. Lett., 62(114), 1989.

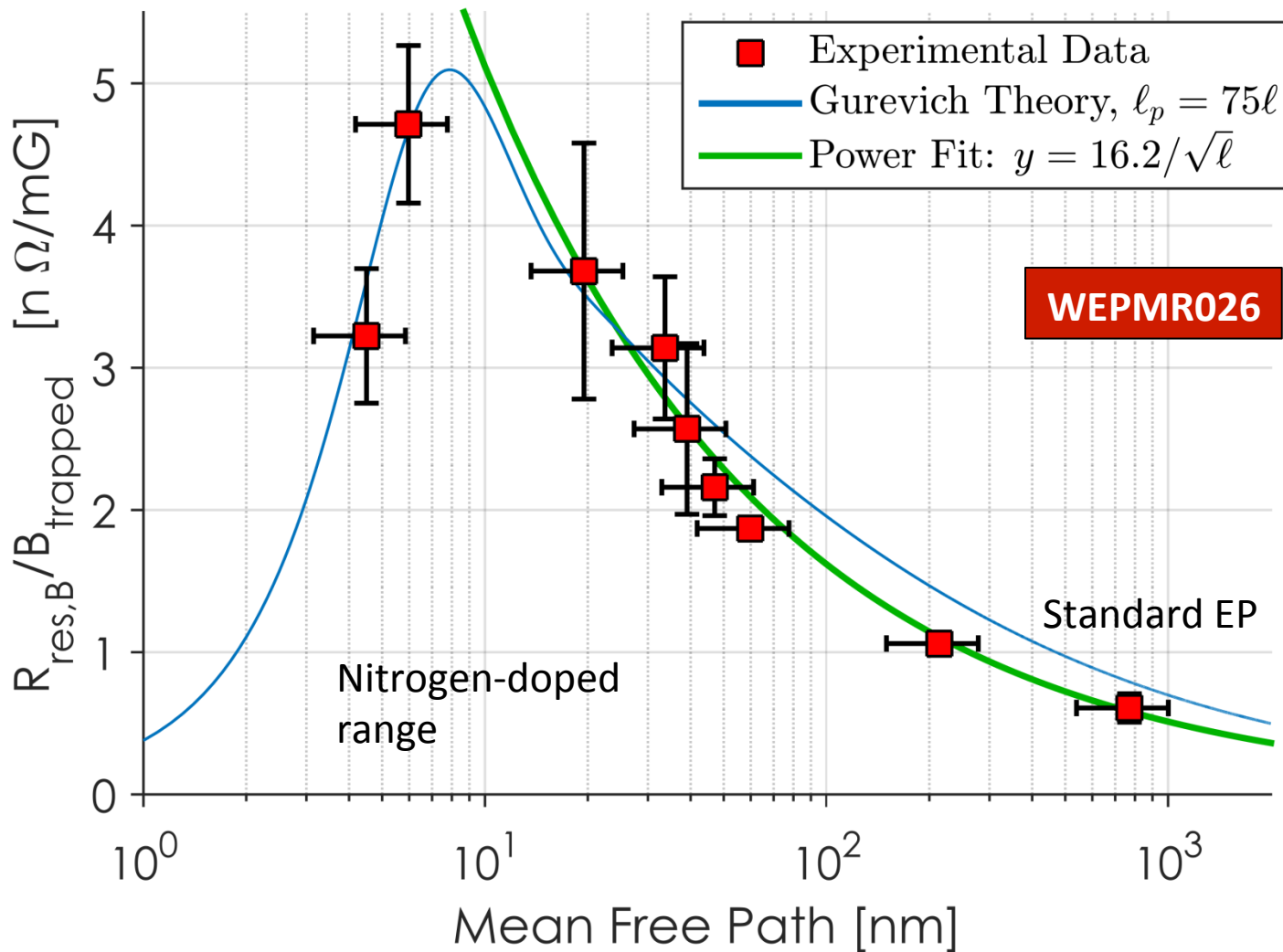




D. Gonnella et al., *Journal of Applied Physics*, 119(073904) 2016.



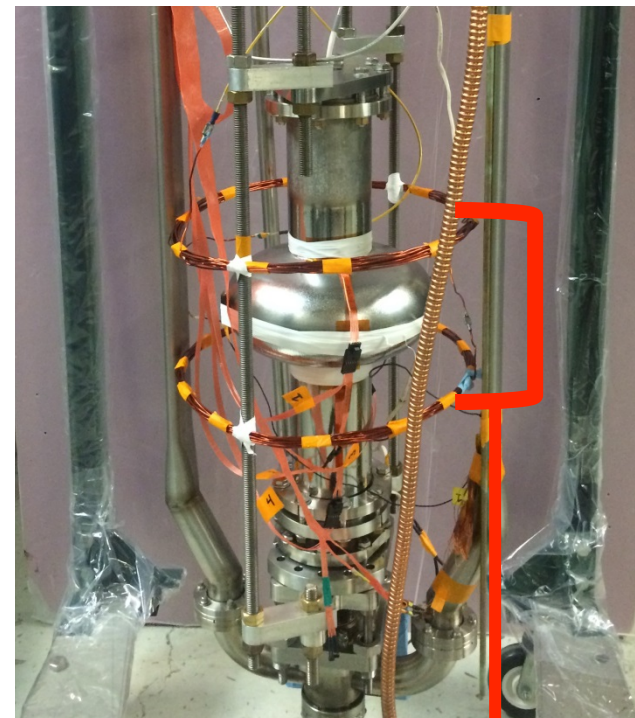
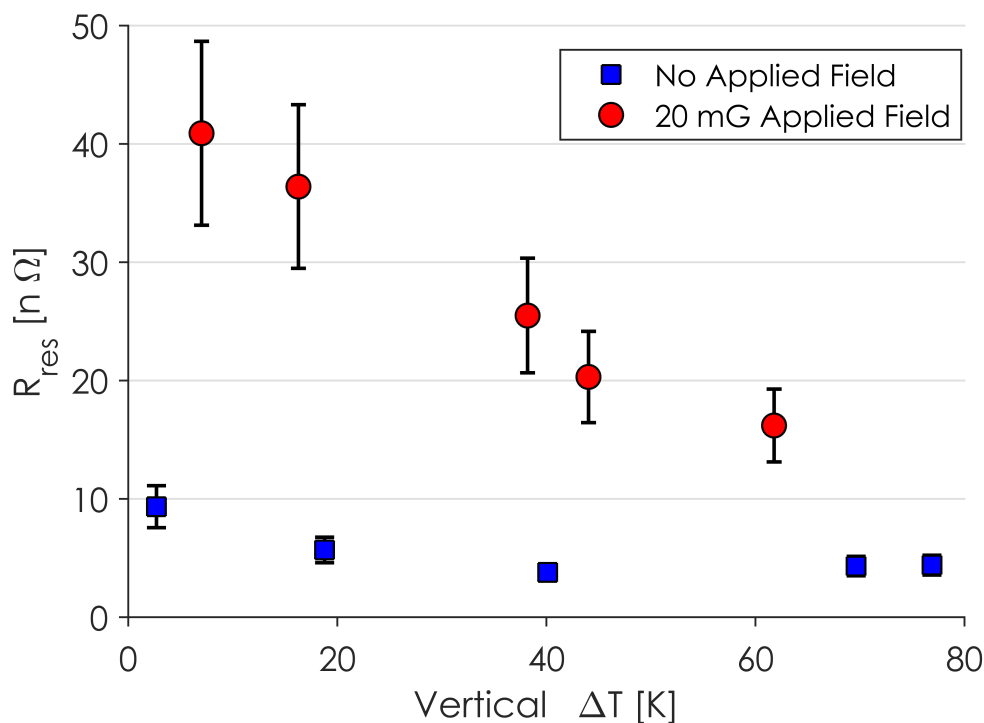
Flux Sensitivity



D. Gonnella et al., *Journal of Applied Physics*, 119(073904) 2016.



- Ways around this sensitivity:
 - Good magnetic shielding
 - Very fast cooldowns
 - Compensation coils



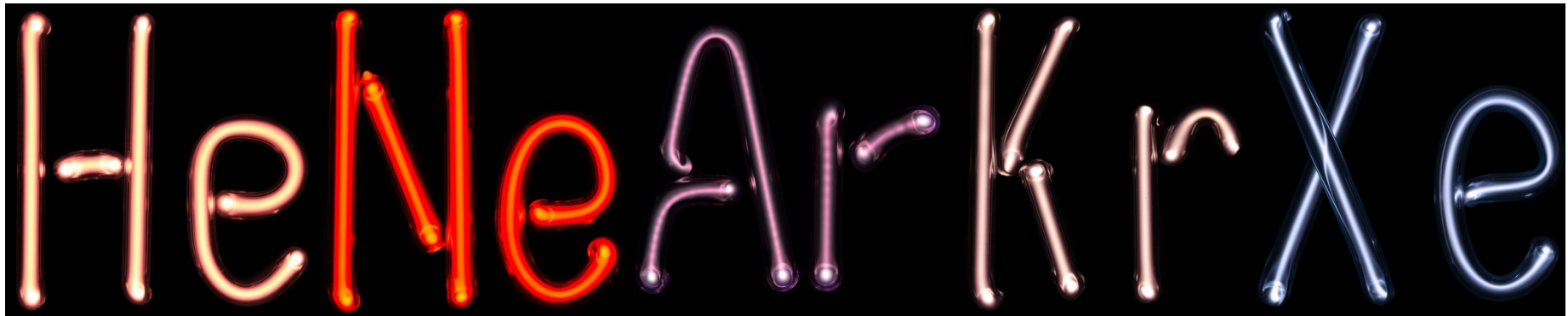
Helmholtz coils



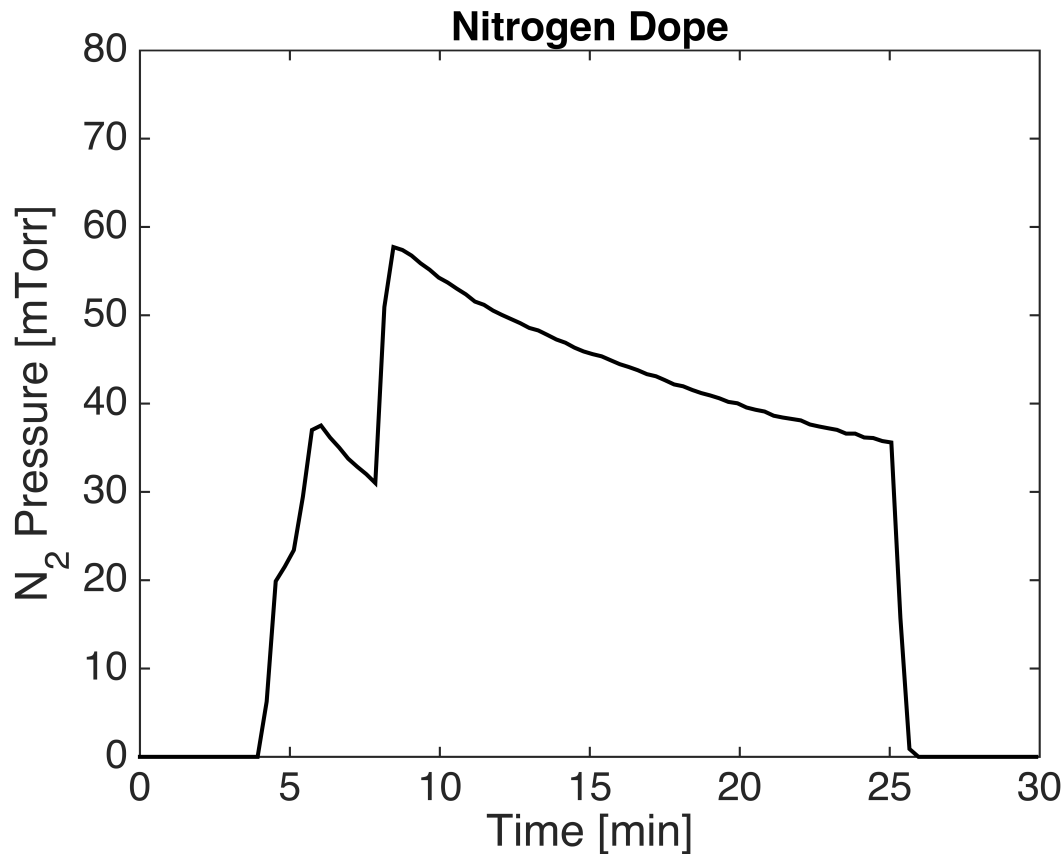
- Nitrogen doping
 - Why dope?
 - Nitrogen Diffusion
 - Benefits of N-doping
 - Field Dependence of Surface Resistance
 - Limitations of N-doping
- Inert Dopants
 - Why alternative dopants?
 - Argon
 - Helium



- Nitrogen is only dopant that has been studied so far:
 - Nitrogen doping has yielded great results
 - Is Nitrogen the best dopant? Are there better dopants?
 - Inert doping could remove chemical etching from the process



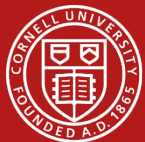
Nitrogen doping so far:



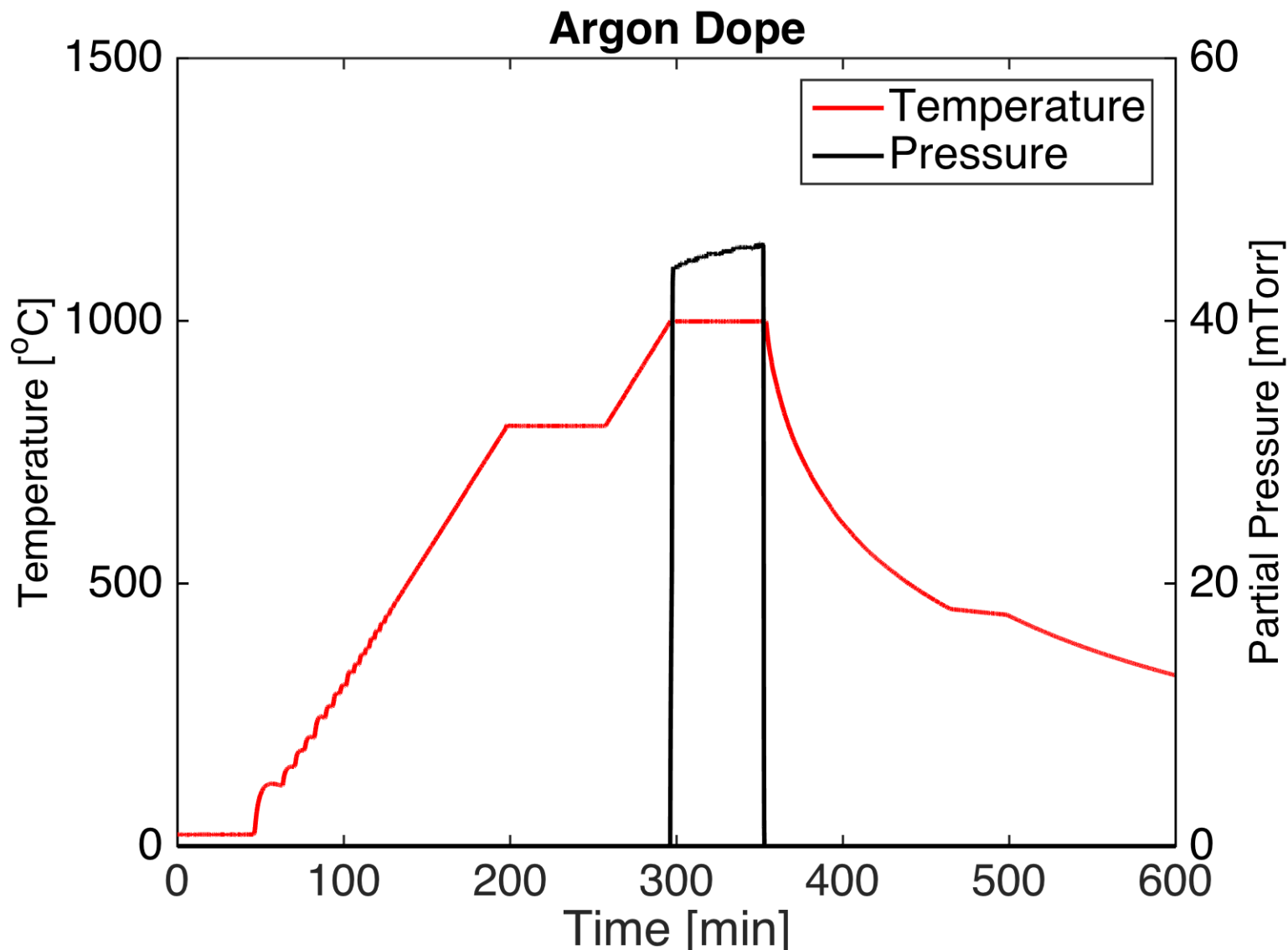
Next Step

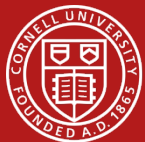


Explore
alternative
dopants: He,
Ne, Ar, ...

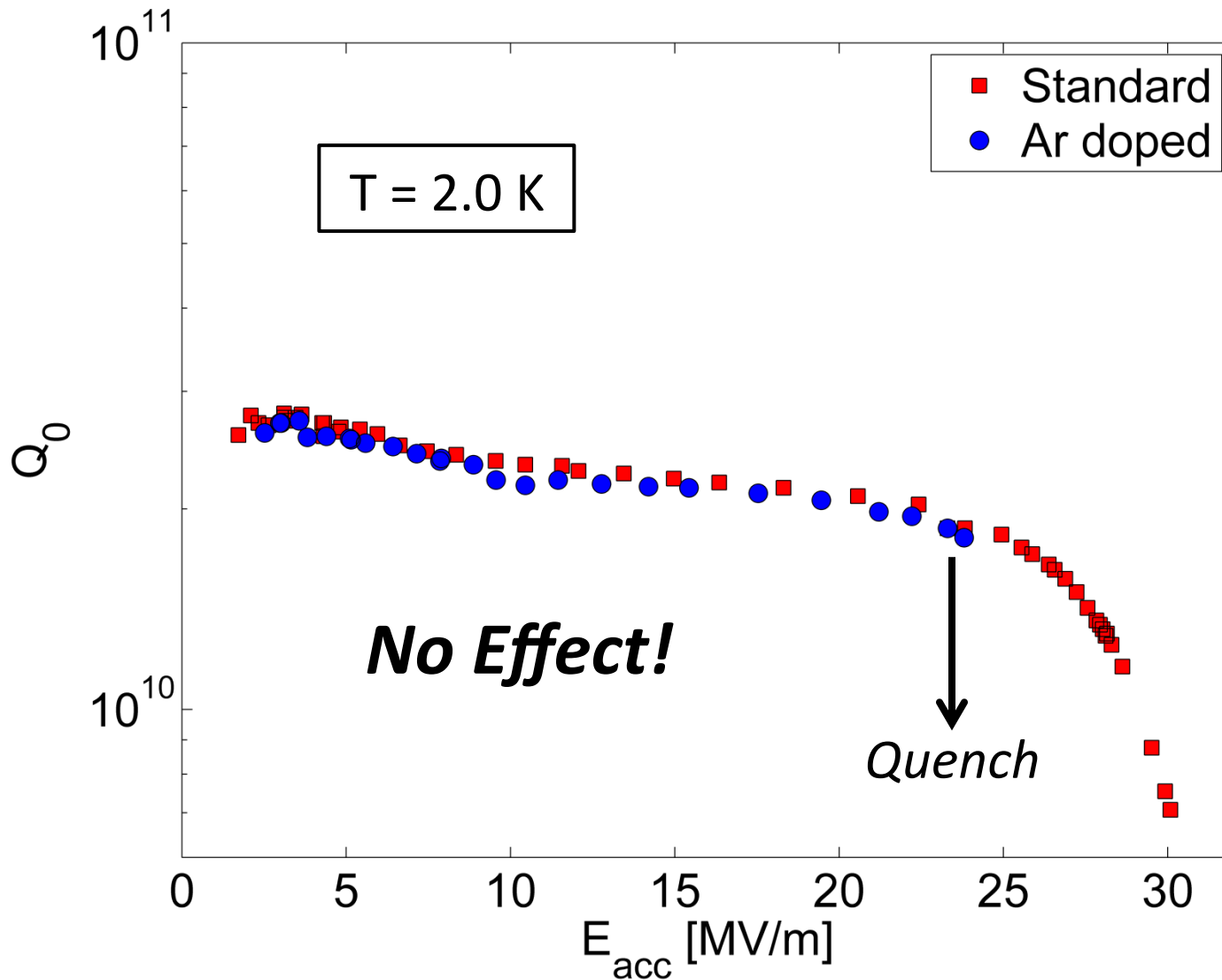


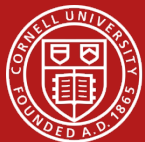
Argon Doping



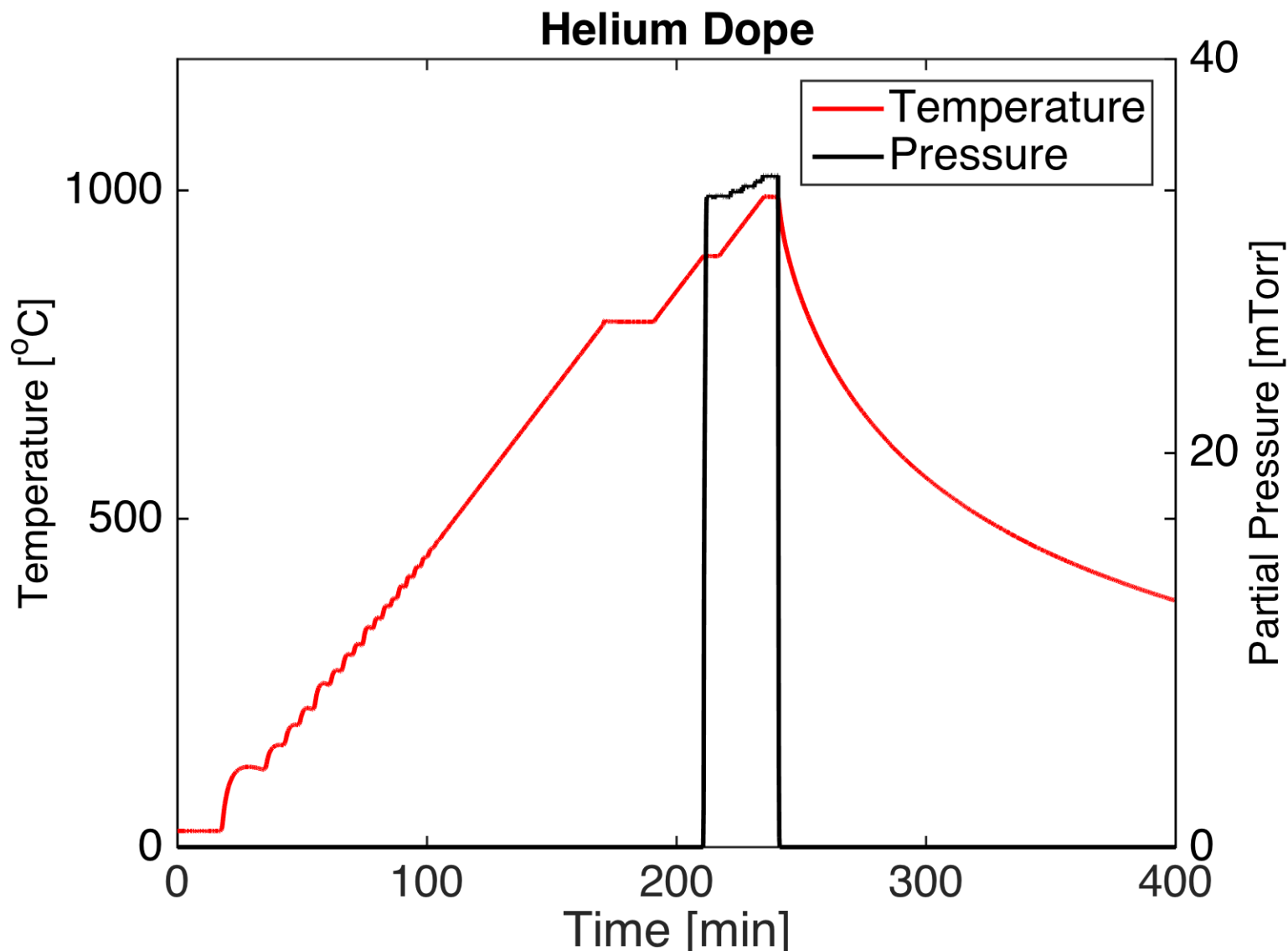


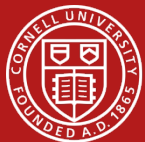
Argon Doping



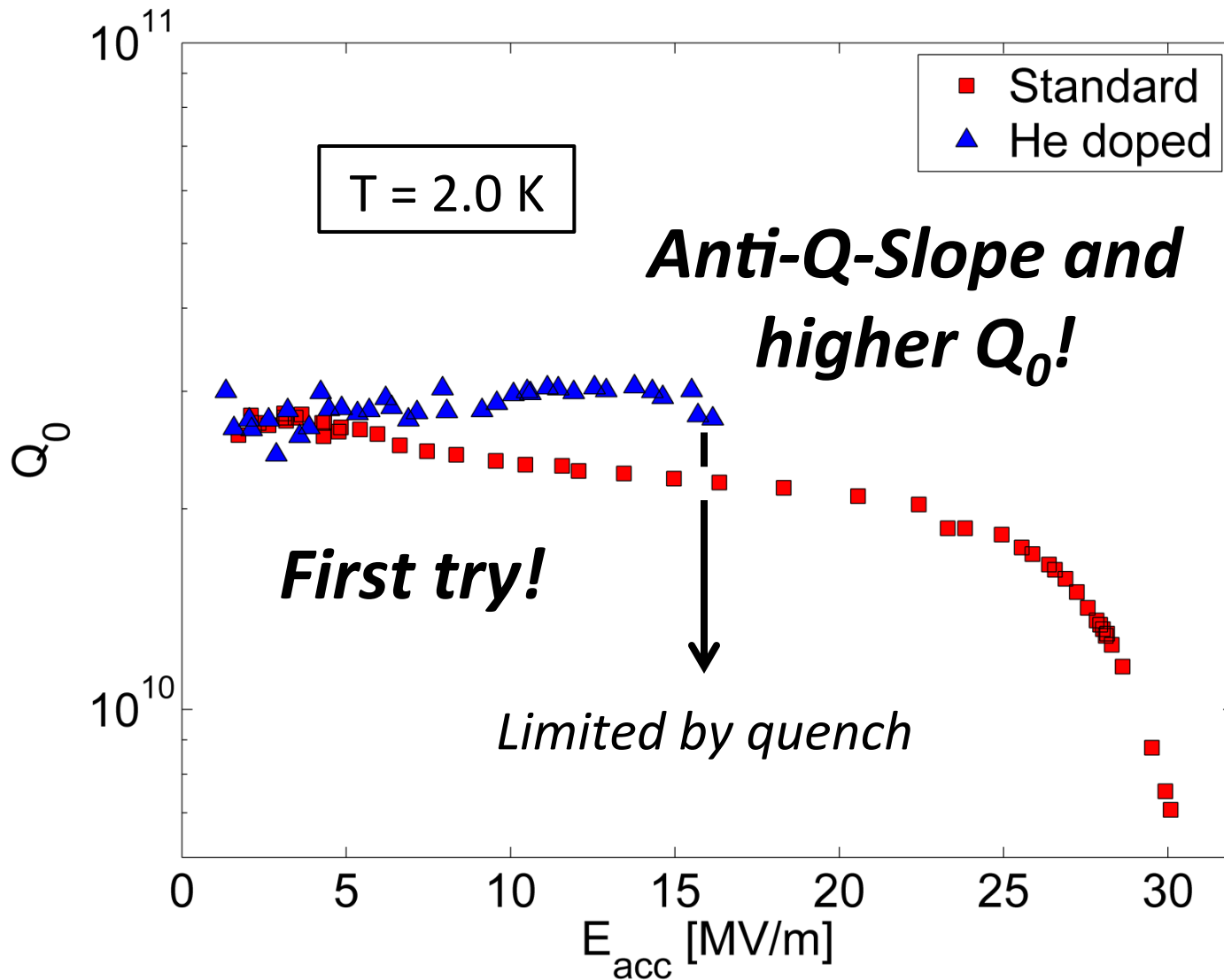


Helium Doping



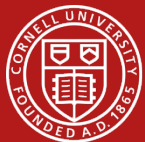


First He Dope!





- Nitrogen doping
 - Very well established method to increase Q_0
 - Significant progress understanding the science of N-doping
 - Drawbacks
 - Trapped flux sensitivity
 - Lower average quench fields
- Inert Doping
 - Argon had no effect
 - First results with helium are exciting
 - Effects similar to nitrogen
 - There is much to be done!



Cornell Laboratory for
Accelerator-based Sciences
and Education (CLASSE)

References & Acknowledgements



***THANK YOU FOR YOUR
ATTENTION!***

ACKNOWLEDGEMENTS

H. Conklin, D. Gonnella, T. Gruber, D. L. Hall, J. J. Kaufman, M. Liepe,
J. T. Maniscalco

